

# Low-Capacitance Solid-State Transformer Control Using an Analytic Filter

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**Abstract**—In the modular three-stage solid-state transformer (SST), each phase is integrated with large dc-link capacitors as energy buffers, to filter the second harmonic capacitor voltage ripple generated due to single-phase power processing. Although large dc-link capacitors reduce the coupling between stages of the SST and simplify the controller design, they compromise the reliability, safety and power density of the SST. Accordingly, a low-capacitance SST is desirable to address these challenges. To provide a high-bandwidth control for the low-capacitance SST, this paper proposes using an analytic filtering scheme rather than the low-pass filters used in conventional SST control schemes. A portion of the second harmonic power ripple in the high-voltage dc-link capacitors is processed by the SST’s dc-dc stage to facilitate the use of low capacitance. The effectiveness of the proposed control is demonstrated through a simulation study in PLECS.

**Keywords:** Analytic filter, low-pass filter, solid-state transformer.

## I. INTRODUCTION

With the rapid growth in the use of renewable energy sources in the power distribution network, the need for smarter technologies to regulate the power flow at critical nodes is increasing. One such solution that provides flexible energy flow control among various sources and loads is a solid-state transformer (SST) [1]-[4]. Fig. 1 depicts a commonly used modular three-stage SST architecture with  $N$  strings [5], [6]. It consists of a cascaded H-bridge (CHB) ac-dc converter in Stage I. Each floating high-voltage (HV) dc-link of Stage I is connected to a dual-active bridge (DAB) dc-dc converter in Stage II. The outputs of all DABs are connected in parallel to form a low-voltage (LV) dc-link. Finally, a two-level inverter converts LVdc to LVac in Stage III.

With large capacitors at the HV and LV dc-links, disturbance decoupling among various stages of the SST happens naturally. Thus, the controller for each stage can be designed independently with well-known control approaches [1], [7]-[9]. However, large capacitors add undesired weight and cost to the system, thus limiting the SSTs application

and competitiveness with respect to the conventional low-frequency transformers. Furthermore, large capacitances are typically achieved by using electrolytic capacitors, which deteriorates the overall SST reliability [10]. Addressing the reliability issue is critical to make the SST an appealing and commercial option. Low-capacitance allows the use of more reliable capacitor technologies, such as film capacitors.

To facilitate the use of low-capacitance in the system, it is necessary to look into:

- 1) High-bandwidth controllers to reduce the strain on the dc-link capacitors during any transient conditions, and
- 2) The maximum allowable second-harmonic power ripple absorbed by the HV dc-link capacitors such that the converters in Stage I do not operate in overmodulation region.

Low-bandwidth outer-control-loops, commonly used in conventional SSTs, are unsuitable for the low-capacitance SST because a reduced electrical inertia leads to increased coupling among various stages of the SST [11], [12]. In this paper, an analytic filtering scheme inspired by that in [10] for low-capacitance static compensators (STATCOMs), is used to improve the bandwidth of the low-capacitance SSTs. In SSTs, the HV dc-link caps interface two stages, whereas in the STATCOM the capacitors are floating. Furthermore, the suggested control is built in a way that allows the HV dc-link and the DAB stage to share a flexible portion of the second harmonic power ripple.

The paper, first, revisits the conventional control used in SSTs in Section II. Then, Section III describes the proposed changes to the conventional control with analytical expressions for the HV dc-link capacitor voltages. Section IV provides simulation results that compare the performance of the conventional and the proposed control of the low-capacitance SSTs. Section V concludes the paper.



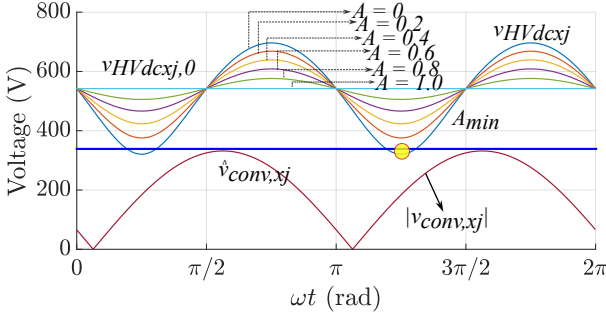


Fig. 4. A visual representation for minimum value of  $A$  required to avoid the overmodulation region of Stage I converter operating with unity power factor and 0.6 modulation index.

#### A. Minimum Percentage of the Second Harmonic Power Through DAB

To realize the low-capacitance SST, a percentage of the second harmonic power (henceforth denoted as  $A$ ) is processed through the DAB stage. Let  $p_{HVxj}$  denote the instantaneous power processed by the  $j^{\text{th}}$  string of Stage I in  $x^{\text{th}}$  phase, which includes a dc power term,  $\bar{P}_{HVxj}$ , and a second-harmonic power ripple term,  $\tilde{p}_{HVxj}$ , namely,

$$p_{HVxj} = v_{convxj} \hat{i}_{HVx} = \bar{P}_{HVxj} + \tilde{p}_{HVxj}, \quad (3)$$

where  $v_{convxj}$  is the converter voltage waveform across the ac-side of the  $j^{\text{th}}$  string of Stage I. Assuming,  $v_{convxj}$  and  $\hat{i}_{HVx}$ , as pure sinusoidal signals, namely,

$$v_{convxj} = \hat{v}_{convxj} \sin(\omega_{HV}t), \quad (4)$$

and,

$$\hat{i}_{HVx} = \hat{i}_{HVx} \sin(\omega_{HV}t + \theta), \quad (5)$$

where  $\theta$  is the phase shift between  $v_{convxj}$  and  $\hat{i}_{HVx}$ , and  $\hat{v}_{convxj}$  and  $\hat{i}_{HVx}$  denote the respective amplitudes. Substitution of (4) and (5) in (3) yields,

$$\bar{P}_{HVxj} = \frac{1}{2} \hat{v}_{conv,xj} \hat{i}_{HV} \cos(\theta), \quad (6)$$

and

$$\tilde{p}_{HVxj} = \frac{1}{2} \hat{v}_{conv,xj} \hat{i}_{HVx} \cos(2\omega_{HV}t + \theta). \quad (7)$$

Note that,  $\hat{v}_{convxj}$ ,  $\hat{i}_{HVx}$ , and  $\theta$  are variables readily available from the control of Stage I in Fig. 2, i.e.,

$$\hat{v}_{conv,xj} = \sqrt{V_{HVdref}^2 + V_{HVqref}^2}, \quad (8)$$

$$\hat{i}_{HVx} = \sqrt{I_{HVdref}^2 + I_{HVqref}^2}, \quad (9)$$

and

$$\theta = \arctan2(V_{HVqref}, V_{HVdref}). \quad (10)$$

Let  $p_{dcxj}$  denote the power processed by the DAB, which consists of (i) the dc power  $\bar{P}_{HVxj}$  in (6) (since the capacitor does not process active power in the steady-state), and (ii) a fraction  $A$  of the second-harmonic power ripple  $\tilde{p}_{HVxj}$  in (7), namely

$$p_{dcxj} = \bar{P}_{HVxj} + A\tilde{p}_{HVxj}. \quad (11)$$

The energy balance equation on the HV dc-link capacitor according to (3) and (11) corresponds to

$$\frac{1}{2} C_{HVdcxj} v_{HVdcxj}^2(t) =$$

$$\frac{1}{2} C_{HVdcxj} v_{HVdcxj,0}^2 + (1-A) \int_0^t \tilde{p}_{HVxj}(t) dt, \quad (12)$$

where  $v_{HVdcxj,0}$  is the average HV dc-link voltage. Substituting (6), (7), and (11) into (12), and solving the integral, yields,

$$v_{HVdcxj}(t) =$$

$$\sqrt{v_{HVdcxj,0}^2 + (1-A) \frac{\hat{v}_{convxj} \hat{i}_{HVx} \sin(2\omega_{HV}t + \theta)}{2\omega_{HV} C_{HVdcxj}}} \quad (13)$$

The condition  $v_{HVdcxj} \geq |v_{HVconvxj}|/N$  must be satisfied at all times to avoid overmodulation, shown in Fig. 4 for different values of  $A$ . Note that  $\sin(2\omega_{HV}t + \theta) = -1$  has been considered, which corresponds to the minimum value of (13). Therefore, the overmodulation inequality results in,

$$A \geq 1 - v_{HVdcxj}^2 \left( \frac{1}{m_{xj}^2} - 1 \right) \frac{2\omega_{HV} C_{HVdcxj}}{\hat{v}_{convxj} \hat{i}_{HVx}} \quad (14)$$

which provides the minimum value of  $A$ ,  $A_{min}$ , to be processed by DAB while preventing overmodulation for a given operating condition, or equivalently, how much the capacitor size  $C_{HVdcxj}$  can be reduced.  $m_{xj}$  is the modulation index of the CHB converter, i.e.,

$$m_{xj} = \frac{\hat{v}_{convxj}}{v_{HVdcxj}}. \quad (15)$$

For example, for a 6.6-kV/400-V, 1.2-MVA (1 p.u.) SST with  $N = 5$  strings, operating at 10 kHz, with an average HV dc-link voltage,  $v_{HVdcxj,0} = 1750\text{V}$  across each string,  $A_{min}$  for two different HV dc-link capacitors,  $C_{HVdcxj} = 83 \mu\text{F}$  and  $20 \mu\text{F}$ , is shown in Fig. 5. When  $C_{HVdcxj} = 83 \mu\text{F}$ , the maximum power ripple processed by the capacitor without overmodulation in the steady-state operation is 0.63 p.u. If larger power values are to be processed, the DAB will take care of it, i.e.,  $A_{min}$  needs to be processed by Stage II. In this case, to transfer 1 p.u. of power, it is essential that  $A \geq 0.4$ . Similarly, for  $C_{HVdcxj} = 20 \mu\text{F}$ , the maximum power processed by the HV dc-link capacitor without overmodulation is 0.16 p.u. However, the maximum value of voltage across the HV dc-link capacitors, i.e.,  $\hat{v}_{HVdcxj}$  reaches 1.28 p.u. To reduce the peak voltage,  $\hat{v}_{HVdcxj}$  to 1.1 p.u., corresponding

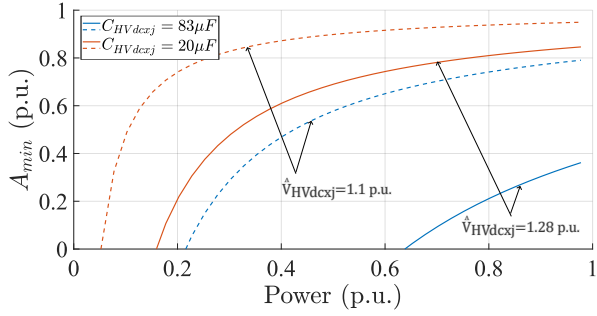


Fig. 5.  $A_{min}$  for a 6.6-kV/400-V, 1.2-MVA (1 p.u.) SST with 5 strings with different  $C_{HVdcxj}$ .

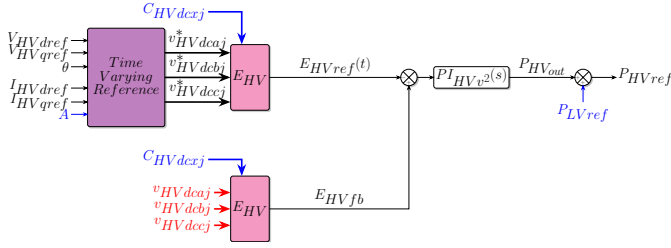


Fig. 6. Proposed control for Stage I with time-varying HV dc-link voltage references, obtained from (13).

value of minimum allowable HV dc-link voltage,  $v_{HVdcxj}(t)$ , is chosen and (13) is solved for the inequality constraint such that  $A_{min}$  curve follows the dashed line for the given choice of  $C_{HVdcxj}$ .

### B. Proposed Control Using Time Varying References for HV DC-Link Energy Control

In the proposed control scheme, two main changes are made to the conventional control block diagrams shown in Figs. 2 and 3. Specifically, the LPF (highlighted in yellow in Fig. 2) is eliminated. For this purpose, a time-varying reference,  $E_{HVref}(t)$  corresponding to (13) is used eliminating the need for an LPF. Since the delay in the ripple estimation is one sample, the filtering is almost instantaneous, allowing a higher control bandwidth straightaway. The modified control diagram for the outer energy loop of Stage I is shown in Fig. 6.

Regarding the DAB control, the feedforward power term  $P_{dcdcff}$ , used in the conventional DAB control of Fig. 3, is modified by adding a fraction  $A$  of power ripple that the DAB must process for overmodulation consideration, such that,

$$P_{dcdcff} = \frac{P_{LVref}}{3N} + A \frac{v_{convxj} \dot{i}_{HVx} - P_{LVref}}{3N}. \quad (16)$$

## IV. SIMULATIONS

To validate the proposed improvements in the low-capacitance SST control, a 6.6-kV/400-V, 1.2-MVA (1 p.u.) SST operating at 10 kHz has been simulated using PLECS simulation platform. A detailed list of parameters used for the simulations is given in Table I.

TABLE I  
SIMULATION PARAMETERS

Definition	Symbol	Value
<b>Stage I</b>		
No. of strings per phase	$N$	5
HV grid voltage amplitude (per phase)	$\hat{v}_{HVx}$	$3.8\sqrt{2}$ kV
HV grid frequency	$f_{HV}$	50 Hz
HV grid equivalent resistance (per phase)	$R_{HVx}$	0.12 $\Omega$
HV grid equivalent inductance (per phase)	$L_{HVx}$	6 mH
Stage I switching frequency	$f_{acdc}$	5 kHz
average HV dc-link voltage	$v_{HVdcxj,0}$	1.7 kV
HV dc-link capacitance	$C_{HVdcxj}$	83 $\mu$ F, 20 $\mu$ F
<b>Stage II</b>		
DAB external inductance	$L_{dab,xj}$	240 $\mu$ H
Transformer turns ratio	$n$	7 : 2
Stage II switching frequency	$f_{dcdc}$	10 kHz
<b>Stage III</b>		
LV grid voltage amplitude (per phase)	$\hat{v}_{LVx}$	$230\sqrt{2}$ V
LV grid frequency	$f_{LV}$	60 Hz
LV equivalent resistance (per phase)	$R_{LVx}$	0.8 m $\Omega$
LV equivalent inductance (per phase)	$L_{LVx}$	40 $\mu$ H
LV dc-link capacitance	$C_{LVdc}$	75 mF
average LV dc-link voltage	$v_{LVdc}$	700 V
Stage III switching frequency	$f_{dcac}$	18 kHz

TABLE II  
COMPARISON OF SIMULATED TEST CASES

$C_{HVdcxj}$	Control	Test Case	$v_{HVdcxj}$ under-shoot	$t_s$	$THD_i$
83 $\mu$ F	LPF	0 p.u. - 0.1 p.u. (Fig. 7)	<0.05 p.u.	0.2 s	0.07%
83 $\mu$ F	(13)	0 p.u. - 0.1 p.u. (Fig. 8)	<0.01 p.u.	<0.01 s	0.07%
20 $\mu$ F	LPF	0 p.u. - 0.1 p.u. (Fig. 9)	0.1 p.u.	0.2 s	2.6%
20 $\mu$ F	(13)	0 p.u. - 0.1 p.u. (Fig. 10)	<0.01 p.u.	0.02 s	2.6%
83 $\mu$ F	(13)	0 p.u. - 1 p.u. (Fig. 11)	<0.01 p.u.	<0.01 s	0.09%

In this study, two different choices of HV dc-link capacitors, 83  $\mu$ F and 20  $\mu$ F, are used. 90% power ripple is considered for Stage II, i.e.,  $A=0.9$ , which is above  $A_{min}$  for both choices of the HV dc-link capacitors, according to Fig. 5. This involves a fixed 10% of twice-fundamental-frequency oscillating power flow into the HV dc-link capacitors.

The results obtained for a step change in active power from 0 p.u. to 0.1 p.u., are summarized in Figs. 7 and 8 for  $C_{HVdcxj} = 83 \mu$ F and in Figs. 9 and 10 for 20  $\mu$ F. To

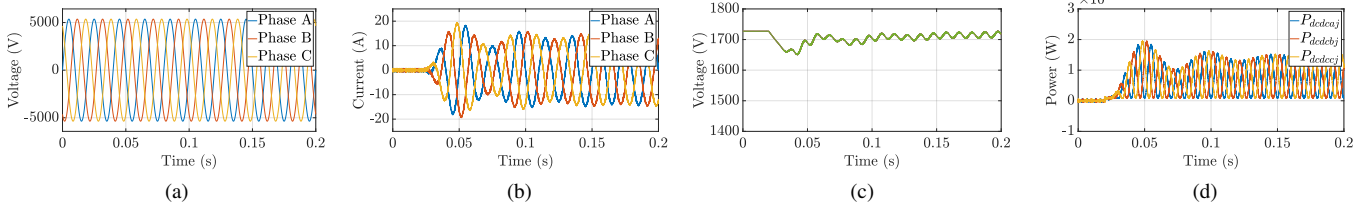


Fig. 7. Simulation study with a step change in active power from 0 p.u. to 0.1 p.u. for  $C_{HVdcoxj} = 83 \mu F$  using LPF: (a) HV grid voltage  $v_{HVx}$ , (b) HV grid current  $i_{HVx}$ , (c) HV dc-link voltages  $v_{HVdcoxj}$ , and (d) power through dc-dc stage  $P_{dcdcoxj}$ .

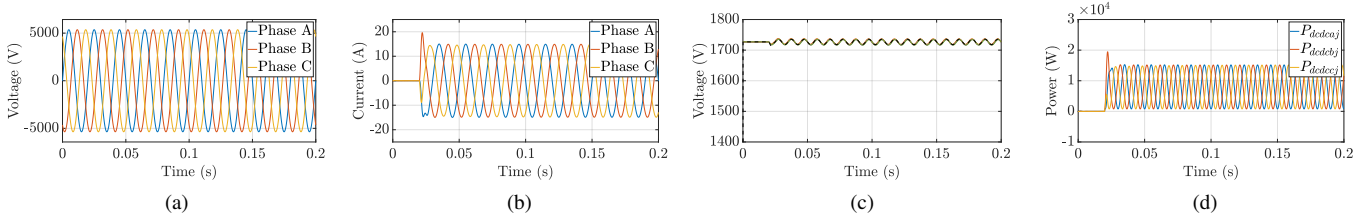


Fig. 8. Simulation study with a step change in active power from 0 p.u. to 0.1 p.u. for  $C_{HVdcoxj} = 83 \mu F$  using (13): (a) HV grid voltage  $v_{HVx}$ , (b) HV grid current  $i_{HVx}$ , (c) HV dc-link voltages  $v_{HVdcoxj}$ , and (d) power through dc-dc stage  $P_{dcdcoxj}$ .

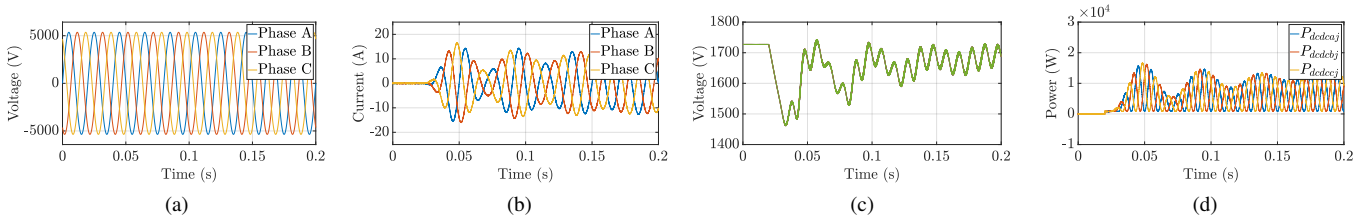


Fig. 9. Simulation study with a step change in active power from 0 p.u. to 0.1 p.u. for  $C_{HVdcoxj} = 20 \mu F$  using LPF: (a) HV grid voltage  $v_{HVx}$ , (b) HV grid current  $i_{HVx}$ , (c) HV dc-link voltages  $v_{HVdcoxj}$ , and (d) power through dc-dc stage  $P_{dcdcoxj}$ .

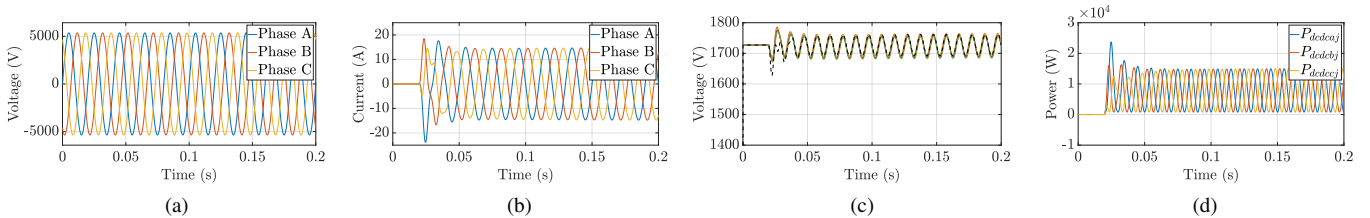


Fig. 10. Simulation study with a step change in active power from 0 p.u. to 0.1 p.u. for  $C_{HVdcoxj} = 20 \mu F$  using (13): (a) HV grid voltage  $v_{HVx}$ , (b) HV grid current  $i_{HVx}$ , (c) HV dc-link voltages  $v_{HVdcoxj}$ , and (d) power through dc-dc stage  $P_{dcdcoxj}$ .

illustrate the effect of the controller, the power feedforward term, i.e.  $P_{LVref}$ , is set to 0. Fig. 7 shows the transient results when adopting a conventional control with LPFs, while Fig. 8 depicts the same waveforms when using the proposed control with time varying reference. Specifically, Figs. 7(c) and 8(c) show the HV dc-link capacitor voltages, and the ripple estimated according to (13) in a dotted line. As seen in these figures, the proposed control shows superior transient responses. Specifically, by using time-varying references, a negligible voltage drop on the  $C_{HVdcoxj}$  is observed as compared to 0.04 p.u. when LPF are used. This is because of high bandwidth for outer-energy controller achieved by eliminating

LPFs. Moreover, the settling time improves from 0.2 s to  $< 0.1$ ms. A similar trend is seen for  $C_{HVdcoxj} = 20 \mu F$ , in Figs. 9 and 10. As the HV dc-link capacitance is reduced, the system is more immune to load transients, and hence, for the given step change in load, the HV dc-link voltage undershoot is increased by 50% when compared with the simulation study for  $C_{HVdcoxj} = 83 \mu F$  and LPFs. But, with the proposed control, the voltage undershoot is reduced to  $\leq 0.01$  p.u. as seen in Fig. 10(c).

Looking at the grid current profile in the steady-state in Figs. 8(b) and 10(b), the  $THD_i$  is increased to 2.6% with  $C_{HVdcoxj} = 20 \mu F$ , compared to 0.07% with  $C_{HVdcoxj} = 83$

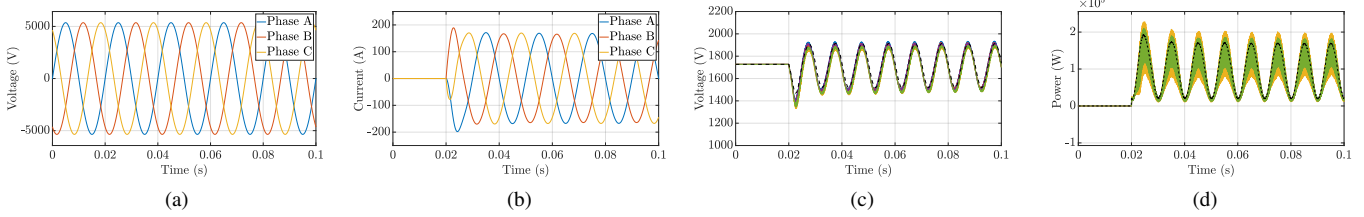


Fig. 11. Simulation study with a step change in active power from 0 p.u. to 1 p.u. for  $C_{HVdcxj} = 83 \mu F$  using (13): (a) HV grid voltage  $v_{HVx}$ , (b) HV grid current  $i_{HVx}$ , (c) HV dc-link voltages  $v_{HVdcxj}$ , and (d) power through dc-dc stage  $P_{dcdcxj}$ .

$\mu F$ . This is because of increased ripple voltage with reduced capacitance. However, the  $THD_i$  remains lower than the standard grid requirements of 5%.

A simulation study for a load transient of 0 to 1 p.u. is shown in Fig. 11 using the proposed time-varying references and a known power feedforward term, i.e.,  $P_{LVref}$ . Even with a substantial transient change in the load, the system remains in safe operating limits owing to the high bandwidth controllers. A detailed comparison on the observed load transient conditions, is summarized in Table. II.

## V. CONCLUSION

This paper has proposed the use of time varying references in SST control system with the aim of increasing the bandwidth of the controller, which is especially relevant in the low-capacitance SST due to its lower electrical inertia. The simulation results obtained from a 1.2-MVA low-capacitance SST, confirm the feasibility and effectiveness of the proposed control system as compared to a conventional control system. With the improvised control of Stage I using time varying references, the undervoltage observed on HV dc-link capacitors during the load transient, is improved at least by 80%. Moreover, the settling time is improved from 0.2 s to  $< 0.02$  s. The  $THD_I$  of the steady-state grid current remains within the standard grid code limit of 5%, assuring the feasibility of low-capacitance SSTs.

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